

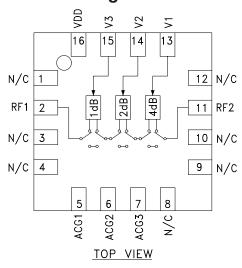
# 1 dB LSB GaAs MMIC 3-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 6.0 GHz

#### Typical Applications

The HMC468LP3 is ideal for:

- Cellular; UMTS/3G Infrastructure
- Fixed Wireless & WLL
- Microwave Radio & VSAT
- Test Equipment

#### Functional Diagram



#### **Features**

1 dB LSB Steps to 7 dB
High IP3: +50 dBm
+/- 0.25 dB Typical Bit Error
Single Control Line Per Bit
Single +5V Supply
3 mm x 3 mm x 1 mm SMT Package

#### General Description

The HMC468LP3 is a broadband 3-bit GaAs IC digital attenuator in a low cost leadless surface mount package. Covering DC to 6.0 GHz, the insertion loss is less than 1 dB typical up to 4 GHz. The attenuator bit values are 1 (LSB), 2 and 4 dB for a total attenuation of 7 dB. Attenuation accuracy is excellent at  $\pm$  0.4 dB typical step error with an IIP3 of +50 dBm. Three control voltage inputs, toggled between 0 and +5V, are used to select each attenuation state. A single Vdd bias of +5V is required.

### Electrical Specifications, $T_A = +25^{\circ}$ C, With Vdd = +5V & Vctl = 0/+5V

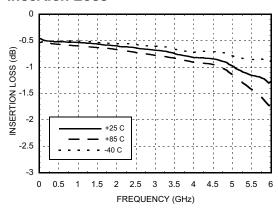
Parameter		Frequency (GHz)	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.5 GHz 2.5 - 4.5 GHz 4.5 - 6.0 GHz		0.7 0.9 1.3	1.0 1.3 1.8	dB dB dB
Attenuation Range		DC - 6.0 GHz		7		dB
Return Loss (RF1 & RF2, All Atten. States)		DC - 4.0 GHz 4.0 - 6.0 GHz		20 15		dB dB
Attenuation Accuracy: (Referenced to Insertion Loss)	All States 1 - 4 dB States 5 - 7 dB States	DC - 2.5 GHz 2.5 - 6.0 GHz 2.5 - 6.0 GHz	± 0.2 + 2% of Atten. Setting Max. ± 0.3 + 3% of Atten. Setting Max. ± 0.4 + 4% of Atten. Setting Max.		dB dB dB	
Input Power for 0.1 dB Compression		0.25 - 6.0 GHz		20		dBm
Input Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)		0.25 - 6.0 GHz		50		dBm
Switching Characteristics		DC - 6.0 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)				110 135		ns ns

<sup>\*</sup> Bypass capacitor connecting ACG1, ACG2 & ACG3 to RF ground required per pin description herein.



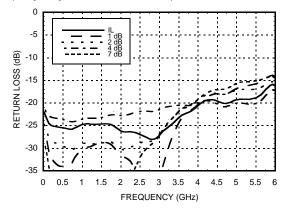
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#### **Insertion Loss**



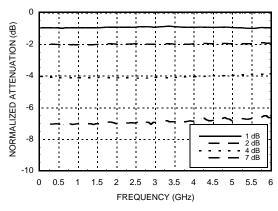
#### Return Loss RF1, RF2

(Only Major States are Shown)

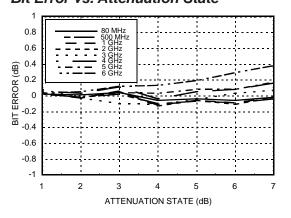


#### Normalized Attenuation

(Only Major States are Shown)

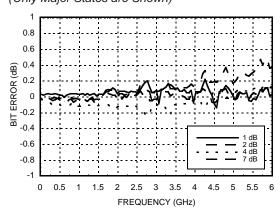


#### Bit Error vs. Attenuation State



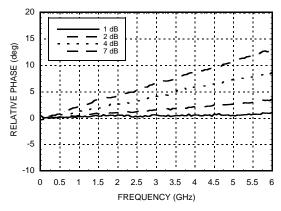
#### Bit Error vs. Frequency

(Only Major States are Shown)



#### Relative Phase vs. Frequency

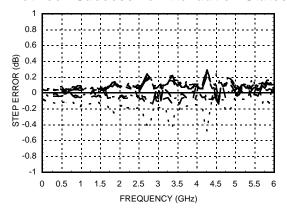
(Only Major States are Shown)





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#### Worst Case Step Error Between Successive Attenuation States



#### Bias Voltage & Current

Vdd Range= +5.0 Vdc ± 10%				
Vdd (Vdc)	ldd (Typ.) (mA)	ldd (Max.) (mA)		
+5.0	1.05	1.8		

### TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to 0.8 Vdc @ -5 uA Typ.
High	+2.0 to +5.0 Vdc @ 40 uA Typ.

#### Truth Table

Control Voltage Input			Attornation Catting	
V1 4 dB	V2 2 dB	V3 1 dB	Attenuation Setting RF1 - RF2	
High	High	High	Reference I.L.	
High	High	Low	1 dB	
High	Low	High	2 dB	
Low	High	High	4 dB	
Low	Low	Low	7 dB	

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.



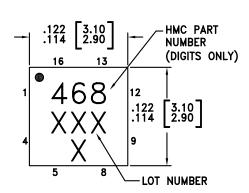
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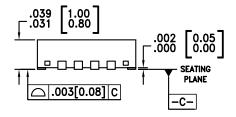
#### Absolute Maximum Ratings

Control Voltage (V1 to V3)	-0.5 Vdc to Vdd +1 Vdc
Bias Voltage (Vdd)	+7.0 Vdc
Staorage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
RF Input Power	+30 dBm

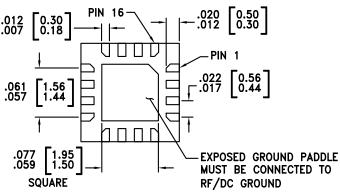
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#### **Outline Drawing**





#### **BOTTOM VIEW**



- 1. MATERIAL PACKAGE BODY: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY
- 3. LEAD AND GROUND PADDLE PLATING: Sn/Pb SOLDER
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 7 PACKAGE WARP SHALL NOT EXCEED 0.05mm
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.



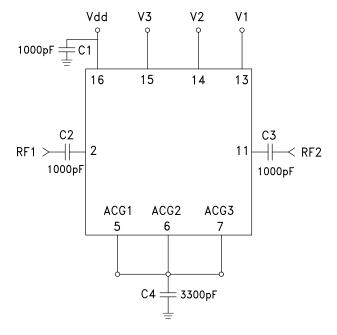


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#### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 4, 8, 9, 10, 12	N/C	These pins should be connected to PCB RF ground to maximize performance.	
2,11	RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required	RF1 (RF2)
13 - 15	V1 - V3	See truth table and control voltage table.	V1 0 133K (V2) (V3) =
5 - 7	ACG1 - ACG3	External capacitor to ground is required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible.	
16	Vdd	Supply Voltage	
	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	0 ==

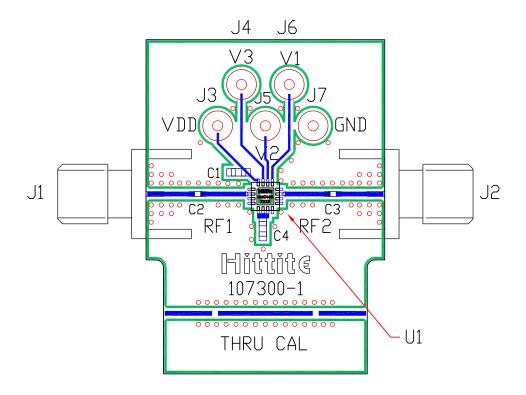
### **Application Circuit**





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#### **Evaluation PCB**



The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

#### List of Material

Item	Description	
J1 - J2	PC Mount SMA Connector	
J3 - J7	DC Pin	
C1	1000 pF Capacitor, 0402 Pkg.	
C2, C3	1000 pF Capacitor, 0603 Pkg.	
C4	3300 pF Capacitor, 0603 Pkg.	
U1	HMC468LP3 Digital Attenuator	
PCB*	107300 Evaluation PCB	
* Circuit Board Material: Rogers 4350		